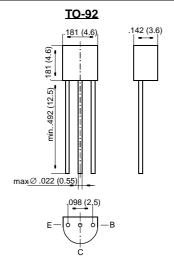
BF421, BF423

Small Signal Transistors (PNP)



Dimensions in inches and (millimeters)

FEATURES

 PNP Silicon Epitaxial Transistors especially suited for application in class-B video output stages of TV receivers and monitors.



 As complementary types, the NPN transistors BF420 and BF422 are recommended.

MECHANICAL DATA

Case: TO-92 Plastic Package Weight: approx. 0.18 g

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

		Symbol	Value	Unit
Collector-Base Voltage	BF421 BF423	-V _{CBO}	300 250	V
Collector-Emitter Voltage	BF423	-V _{CEO}	250	V
Collector-Emitter Voltage	BF421	-V _{CER}	300	V
Emitter-Base Voltage		-V _{EBO}	5	V
Collector Current		-I _C	50	mA
Peak Collector Current		-I _{CM}	100	mA
Power Dissipation at T _{amb} = 25 °C		P _{tot}	830 ¹⁾	mW
Junction Temperature		Tj	150	°C
Storage Temperature Range		T _S	-65 to +150	°C

¹⁾ Valid provided that leads are kept at ambient temperature at a distance of 2 mm from case.



BF421, BF423

ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

	Symbol	Min.	Тур.	Max.	Unit
Collector-Base Breakdown Voltage at $-I_C = 100 \mu A$, $I_E = 0$ BF423	-V _(BR) CBO -V _(BR) CBO	300 250	-		V
Collector-Emitter Breakdown Voltage BF423 at -I _C = 10 mA, I _B = 0	-V _(BR) CEO	250	-	_	V
Collector-Emitter Breakdown Voltage BF421 at R_{BE} = 2.7 $k\Omega$, at $-I_{C}$ = 10 mA	-V _(BR) CER	300	-	_	V
Emitter-Base Breakdown Voltage at $-I_E = 100 \mu A$, $I_C = 0$	-V _{(BR)EBO}	5	-	_	V
Collector-Base Cutoff Current at $-V_{CB} = 200 \text{ V}, I_E = 0$	-I _{CBO}	_	_	10	nA
Collector-Emitter Cutoff Current at R_{BE} = 2.7 k Ω , $-V_{CE}$ = 250 V at R_{BE} = 2.7 k Ω , $-V_{CE}$ = 200 V, T_j = 150 °C	-I _{CER}			50 10	nΑ μΑ
Collector Saturation Voltage at $-I_C = 30$ mA, $-I_B = 5$ mA	-V _{CEsat}	_	-	0.8	V
DC Current Gain at $-V_{CE} = 20 \text{ V}$, $-I_{C} = 25 \text{ mA}$	h _{FE}	50	_	_	_
Gain-Bandwidth Product at $-V_{CE} = 10 \text{ V}$, $-I_{C} = 10 \text{ mA}$	f _T	60	-	_	MHz
Feedback Capacitance at -V _{CE} = 30 V, -I _C = 0, f = 1 MHz	C _{re}	_	-	1.6	pF
Thermal Resistance Junction to Ambient Air	R _{thJA}	_	_	150 ¹⁾	K/W

¹⁾ Valid provided that leads are kept at ambient temperature at a distance of 2 mm from case.

